

PESD5Zx series

Low capacitance unidirectional ESD protection diodes

Rev. 02 — 4 April 2008

Product data sheet

1. Product profile

1.1 General description

Low capacitance unidirectional ElectroStatic Discharge (ESD) protection diodes in a SOD523 (SC-79) ultra small and flat lead Surface-Mounted Device (SMD) plastic package designed to protect one signal line from the damage caused by ESD and other transients.

Table 1. Product overview

| Type number | Package | | Configuration |
|-------------|---------|-------|---------------|
| | NXP | JEITA | |
| PESD5Z2.5 | SOD523 | SC-79 | single |
| PESD5Z3.3 | | | |
| PESD5Z5.0 | | | |
| PESD5Z6.0 | | | |
| PESD5Z7.0 | | | |
| PESD5Z12 | | | |

1.2 Features

- ESD protection of one line
- Low diode capacitance
- Max. peak pulse power: $P_{PP} = 260 \text{ W}$
- Low clamping voltage: $V_{CL} = 15 \text{ V}$
- Low leakage current: $I_{RM} < 1 \text{ nA}$
- ESD protection up to 30 kV
- IEC 61000-4-2; level 4 (ESD)
- IEC 61000-4-5 (surge); $I_{PP} = 20 \text{ A}$

1.3 Applications

- Computers and peripherals
- Audio and video equipment
- Cellular handsets and accessories
- 10/100/1000 Mbit/s Ethernet
- Communication systems
- Portable electronics
- Subscriber Identity Module (SIM) card protection
- FireWire
- High-speed data lines

1.4 Quick reference data

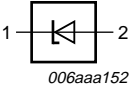
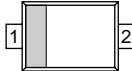
Table 2. Quick reference data

$T_{amb} = 25\text{ }^{\circ}\text{C}$ unless otherwise specified.

| Symbol | Parameter | Conditions | Min | Typ | Max | Unit |
|------------------|--------------------------|--------------------------------------|-----|-----|------|------|
| Per diode | | | | | | |
| V_{RWM} | reverse standoff voltage | | | | | |
| | PESD5Z2.5 | | - | - | 2.5 | V |
| | PESD5Z3.3 | | - | - | 3.3 | V |
| | PESD5Z5.0 | | - | - | 5.0 | V |
| | PESD5Z6.0 | | - | - | 6.0 | V |
| | PESD5Z7.0 | | - | - | 7.0 | V |
| | PESD5Z12 | | - | - | 12.0 | V |
| C_d | diode capacitance | $f = 1\text{ MHz}; V_R = 0\text{ V}$ | | | | |
| | PESD5Z2.5 | | - | 229 | 300 | pF |
| | PESD5Z3.3 | | - | 172 | 200 | pF |
| | PESD5Z5.0 | | - | 89 | 150 | pF |
| | PESD5Z6.0 | | - | 78 | 150 | pF |
| | PESD5Z7.0 | | - | 69 | 150 | pF |
| | PESD5Z12 | | - | 35 | 75 | pF |

2. Pinning information

Table 3. Pinning

| Pin | Description | Simplified outline | Symbol |
|-----|-------------|--|---|
| 1 | cathode | [1] |  |
| 2 | anode |  | |

[1] The marking bar indicates the cathode.

3. Ordering information

Table 4. Ordering information

| Type number | Package | | Version |
|-------------|---------|--|---------|
| | Name | Description | |
| PESD5Z2.5 | SC-79 | plastic surface-mounted package; 2 leads | SOD523 |
| PESD5Z3.3 | | | |
| PESD5Z5.0 | | | |
| PESD5Z6.0 | | | |
| PESD5Z7.0 | | | |
| PESD5Z12 | | | |

4. Marking

Table 5. Marking codes

| Type number | Marking code |
|-------------|--------------|
| PESD5Z2.5 | N7 |
| PESD5Z3.3 | N8 |
| PESD5Z5.0 | N9 |
| PESD5Z6.0 | NA |
| PESD5Z7.0 | NB |
| PESD5Z12 | NC |

5. Limiting values

Table 6. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

| Symbol | Parameter | Conditions | Min | Max | Unit |
|-------------------|----------------------|--------------------------|--------|------|------|
| Per diode | | | | | |
| P _{PP} | peak pulse power | t _p = 8/20 μs | [1][2] | | |
| | PESD5Z2.5 | | - | 260 | W |
| | PESD5Z3.3 | | - | 260 | W |
| | PESD5Z5.0 | | - | 180 | W |
| | PESD5Z6.0 | | - | 180 | W |
| | PESD5Z7.0 | | - | 180 | W |
| | PESD5Z12 | | - | 200 | W |
| I _{PP} | peak pulse current | t _p = 8/20 μs | [1][2] | | |
| | PESD5Z2.5 | | - | 20 | A |
| | PESD5Z3.3 | | - | 20 | A |
| | PESD5Z5.0 | | - | 10 | A |
| | PESD5Z6.0 | | - | 10 | A |
| | PESD5Z7.0 | | - | 10 | A |
| | PESD5Z12 | | - | 6 | A |
| Per device | | | | | |
| T _j | junction temperature | | - | 150 | °C |
| T _{amb} | ambient temperature | | -65 | +150 | °C |
| T _{stg} | storage temperature | | -65 | +150 | °C |

[1] Non-repetitive current pulse 8/20 μs exponential decay waveform according to IEC 61000-4-5.

[2] Measured from pin 1 to 2.

Table 7. ESD maximum ratings

| Symbol | Parameter | Conditions | Min | Max | Unit |
|------------------|---------------------------------|-----------------------------------|--------|------|------|
| Per diode | | | | | |
| V_{ESD} | electrostatic discharge voltage | | | | |
| | PESD5Zx series | IEC 61000-4-2 (contact discharge) | [1][2] | - 30 | kV |
| | | machine model | - | 400 | V |
| | | MIL-STD-883 (human body model) | - | 10 | kV |

[1] Device stressed with ten non-repetitive ESD pulses.

[2] Measured from pin 1 to 2.

Table 8. ESD standards compliance

| Standard | Conditions |
|---|---------------------------------|
| Per diode | |
| IEC 61000-4-2; level 4 (ESD) | > 15 kV (air); > 8 kV (contact) |
| MIL-STD-883; class 3 (human body model) | > 4 kV |

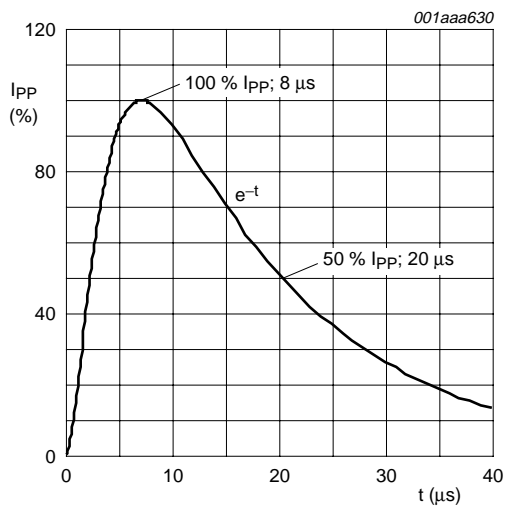


Fig 1. 8/20 μs pulse waveform according to IEC 61000-4-5

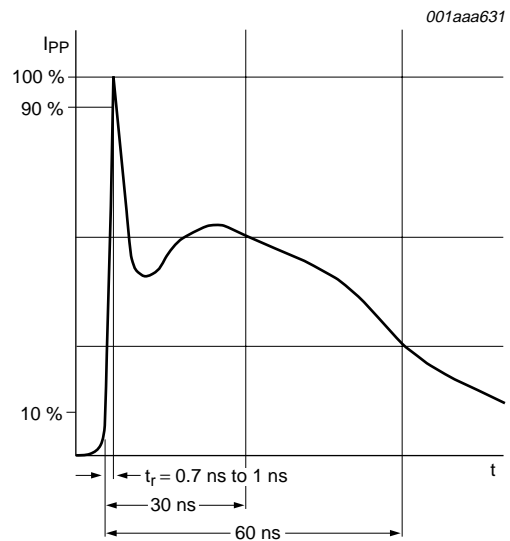


Fig 2. ESD pulse waveform according to IEC 61000-4-2

6. Characteristics

Table 9. Characteristics
T_{amb} = 25 °C unless otherwise specified.

| Symbol | Parameter | Conditions | Min | Typ | Max | Unit |
|------------------|--------------------------|---------------------------------|------------------------|-----|------|------|
| Per diode | | | | | | |
| V _{RWM} | reverse standoff voltage | | | | | |
| | PESD5Z2.5 | | - | - | 2.5 | V |
| | PESD5Z3.3 | | - | - | 3.3 | V |
| | PESD5Z5.0 | | - | - | 5.0 | V |
| | PESD5Z6.0 | | - | - | 6.0 | V |
| | PESD5Z7.0 | | - | - | 7.0 | V |
| | PESD5Z12 | | - | - | 12.0 | V |
| I _{RM} | reverse leakage current | | | | | |
| | PESD5Z2.5 | V _{RWM} = 2.5 V | - | 0.5 | 6 | μA |
| | PESD5Z3.3 | V _{RWM} = 3.3 V | - | 8 | 50 | nA |
| | PESD5Z5.0 | V _{RWM} = 5.0 V | - | 5 | 50 | nA |
| | PESD5Z6.0 | V _{RWM} = 6.0 V | - | 2 | 10 | nA |
| | PESD5Z7.0 | V _{RWM} = 7.0 V | - | < 1 | 10 | nA |
| | PESD5Z12 | V _{RWM} = 12.0 V | - | < 1 | 10 | nA |
| V _{BR} | breakdown voltage | I _R = 1 mA | | | | |
| | PESD5Z2.5 | | 4 | - | - | V |
| | PESD5Z3.3 | | 5 | - | - | V |
| | PESD5Z5.0 | | 6.2 | - | - | V |
| | PESD5Z6.0 | | 6.8 | - | - | V |
| | PESD5Z7.0 | | 7.5 | - | - | V |
| | PESD5Z12 | | 14.1 | - | - | V |
| C _d | diode capacitance | f = 1 MHz; V _R = 0 V | | | | |
| | PESD5Z2.5 | | - | 229 | 300 | pF |
| | PESD5Z3.3 | | - | 172 | 200 | pF |
| | PESD5Z5.0 | | - | 89 | 150 | pF |
| | PESD5Z6.0 | | - | 78 | 150 | pF |
| | PESD5Z7.0 | | - | 69 | 150 | pF |
| | PESD5Z12 | | - | 35 | 75 | pF |
| V _{CL} | clamping voltage | I _{PP} = 5 A | [1][2] | | | |
| | PESD5Z2.5 | | - | 8 | 9 | V |
| | PESD5Z3.3 | | - | 8 | 10 | V |
| | PESD5Z5.0 | | - | 12 | 13 | V |
| | PESD5Z6.0 | | - | 12 | 13 | V |
| | PESD5Z7.0 | | - | 14 | 15 | V |
| | PESD5Z12 | | - | 27 | 30 | V |

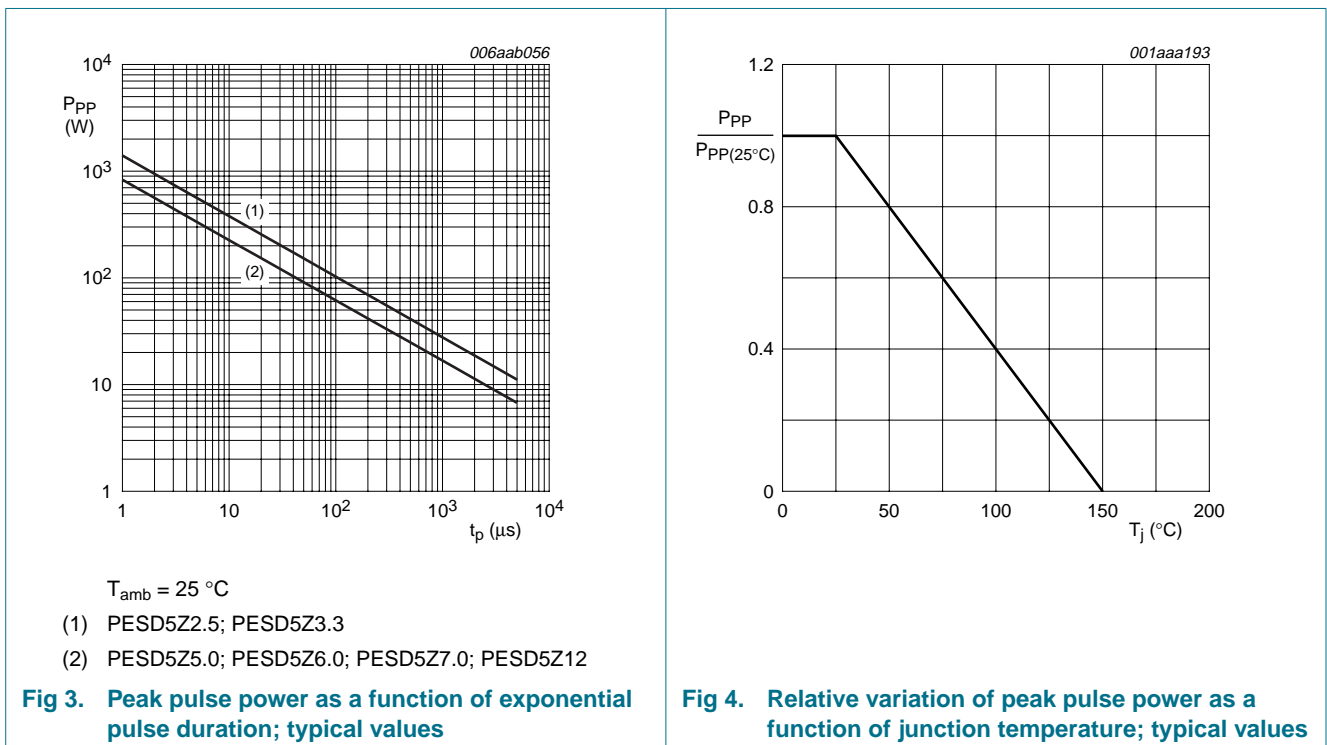
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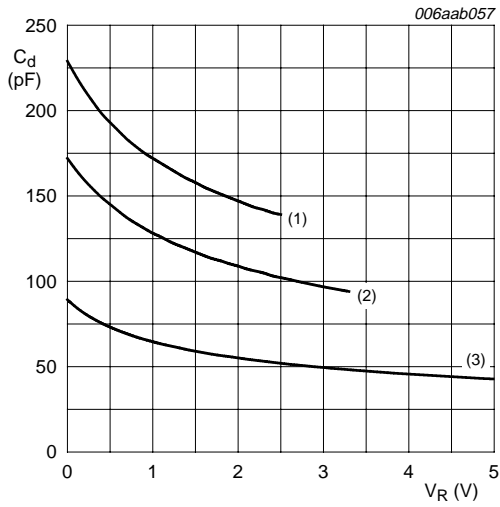
$T_{amb} = 25\text{ }^{\circ}\text{C}$ unless otherwise specified.

| Symbol | Parameter | Conditions | Min | Typ | Max | Unit |
|-----------|-------------------------|------------------------|--------|-----|-----|----------|
| V_{CL} | clamping voltage | | [1][2] | | | |
| | PESD5Z2.5 | $I_{PP} = 20\text{ A}$ | - | - | 15 | V |
| | PESD5Z3.3 | $I_{PP} = 20\text{ A}$ | - | - | 18 | V |
| | PESD5Z5.0 | $I_{PP} = 10\text{ A}$ | - | - | 18 | V |
| | PESD5Z6.0 | $I_{PP} = 10\text{ A}$ | - | - | 18 | V |
| | PESD5Z7.0 | $I_{PP} = 10\text{ A}$ | - | - | 19 | V |
| | PESD5Z12 | $I_{PP} = 6\text{ A}$ | - | - | 35 | V |
| r_{dif} | differential resistance | $I_R = 5\text{ mA}$ | | | | |
| | PESD5Z2.5 | | - | - | 60 | Ω |
| | PESD5Z3.3 | | - | - | 10 | Ω |
| | PESD5Z5.0 | | - | - | 15 | Ω |
| | PESD5Z6.0 | | - | - | 15 | Ω |
| | PESD5Z7.0 | | - | - | 15 | Ω |
| | PESD5Z12 | | - | - | 40 | Ω |

[1] Non-repetitive current pulse 8/20 μs exponential decay waveform according to IEC 61000-4-5.

[2] Measured from pin 1 to 2.

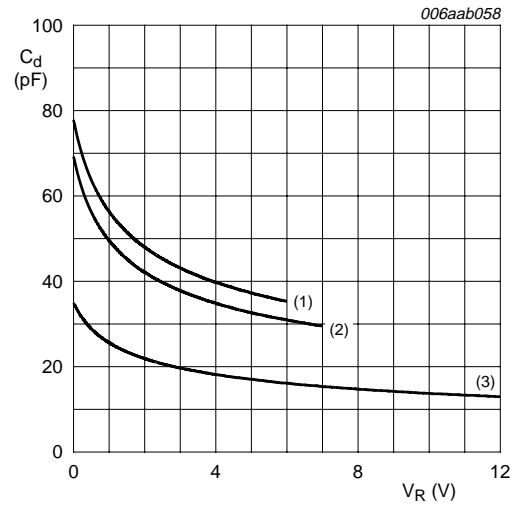




f = 1 MHz; T_{amb} = 25 °C

- (1) PESD5Z2.5
- (2) PESD5Z3.3
- (3) PESD5Z5.0

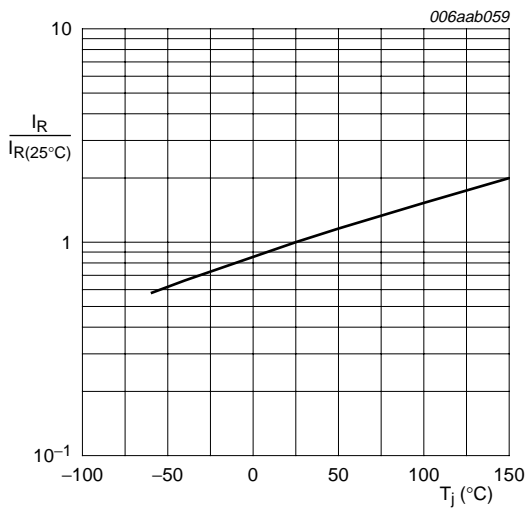
Fig 5. Diode capacitance as a function of reverse voltage; typical values



f = 1 MHz; T_{amb} = 25 °C

- (1) PESD5Z6.0
- (2) PESD5Z7.0
- (3) PESD5Z12

Fig 6. Diode capacitance as a function of reverse voltage; typical values



PESD5Z2.5; V_{RWM} = 2.5 V
 PESD5Z3.3; V_{RWM} = 3.3 V
 I_R is less than 50 nA at 150 °C for:
 PESD5Z5.0; V_{RWM} = 5.0 V
 PESD5Z6.0; V_{RWM} = 6.0 V
 PESD5Z7.0; V_{RWM} = 7.0 V
 PESD5Z12; V_{RWM} = 12.0 V

Fig 7. Relative variation of reverse current as a function of junction temperature; typical values

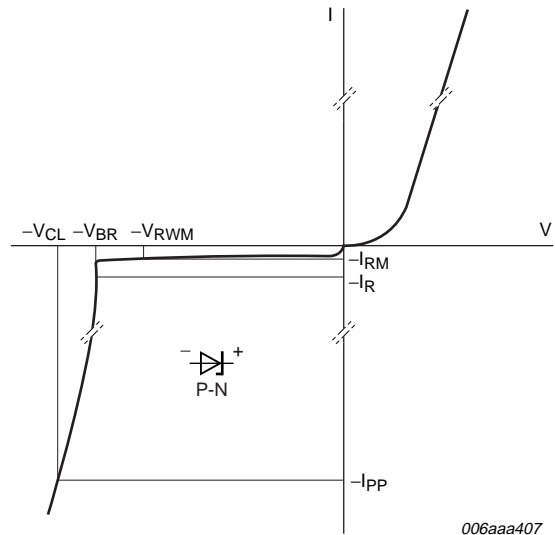
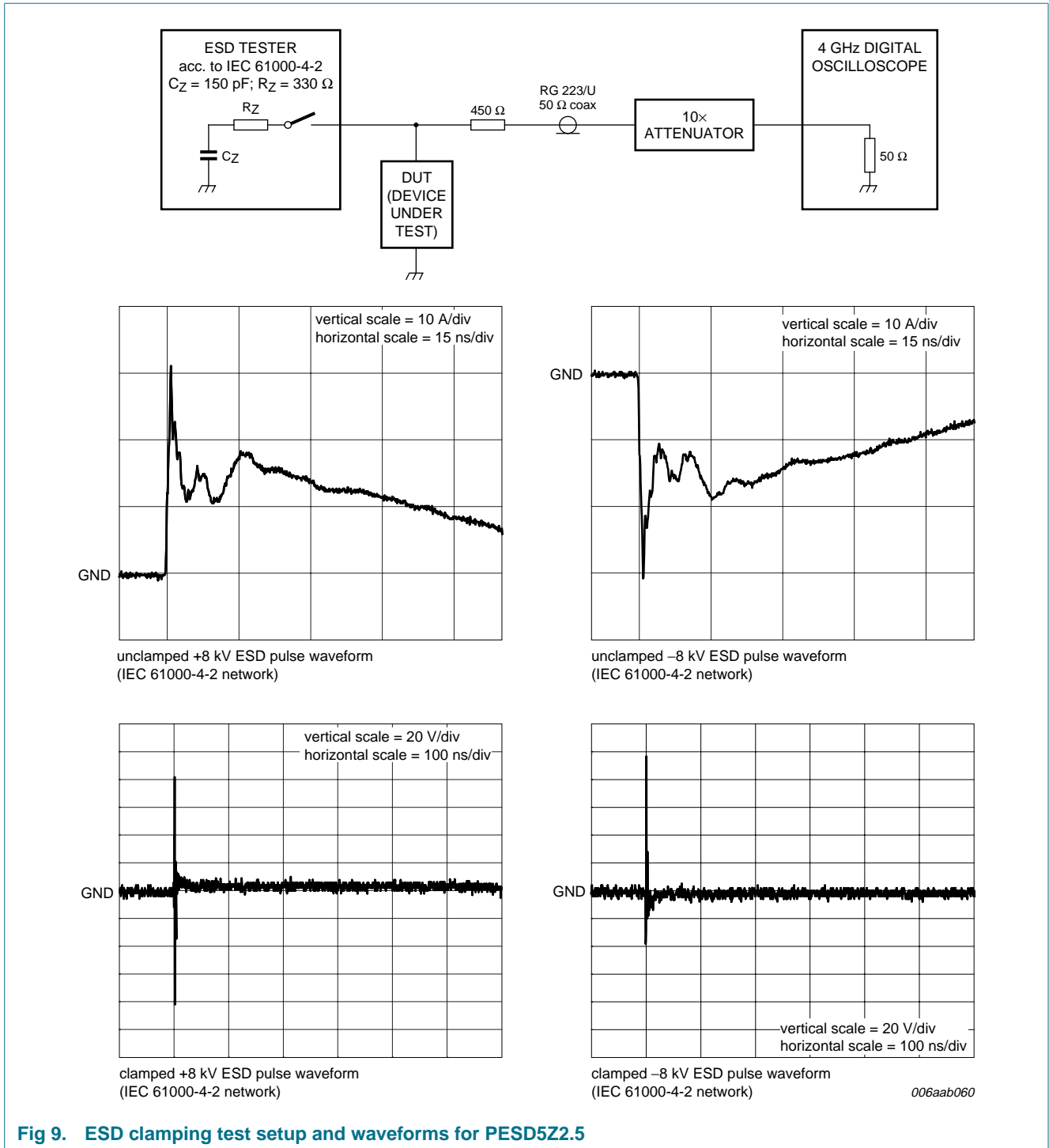


Fig 8. V-I characteristics for a unidirectional ESD protection diode



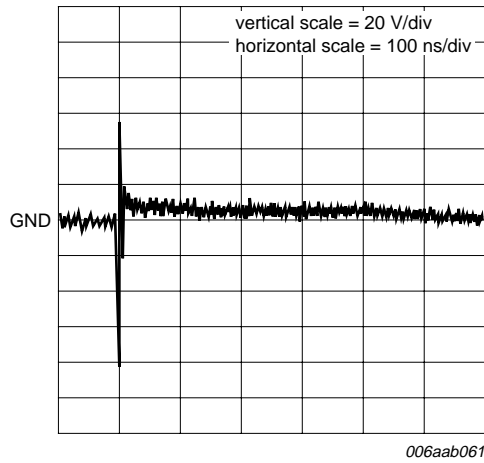


Fig 10. PESD5Z3.3: Clamped +8 kV ESD pulse waveform (IEC 61000-4-2 network)

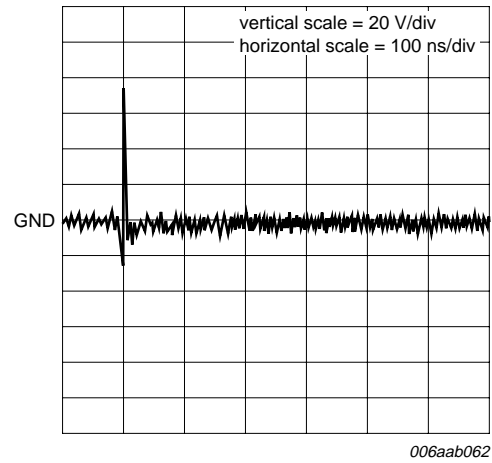


Fig 11. PESD5Z3.3: Clamped -8 kV ESD pulse waveform (IEC 61000-4-2 network)

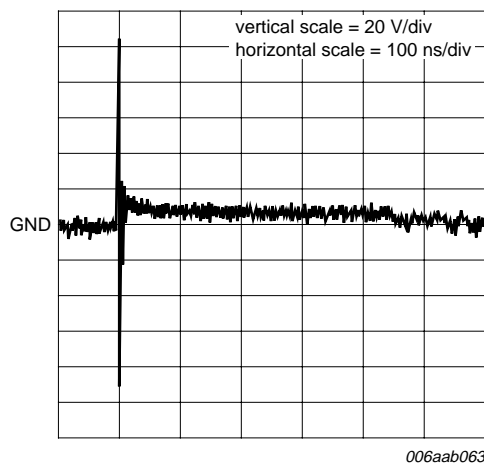


Fig 12. PESD5Z5.0: Clamped +8 kV ESD pulse waveform (IEC 61000-4-2 network)

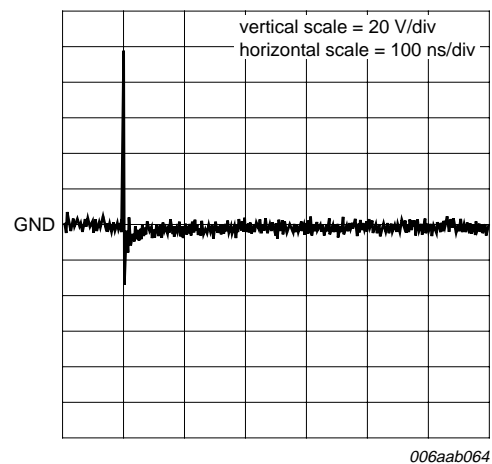


Fig 13. PESD5Z5.0: Clamped -8 kV ESD pulse waveform (IEC 61000-4-2 network)

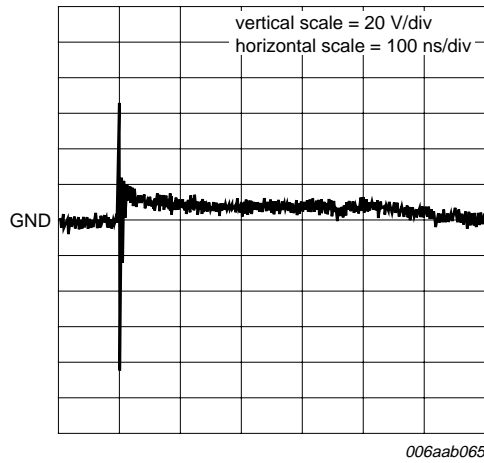


Fig 14. PESD5Z6.0: Clamped +8 kV ESD pulse waveform (IEC 61000-4-2 network)

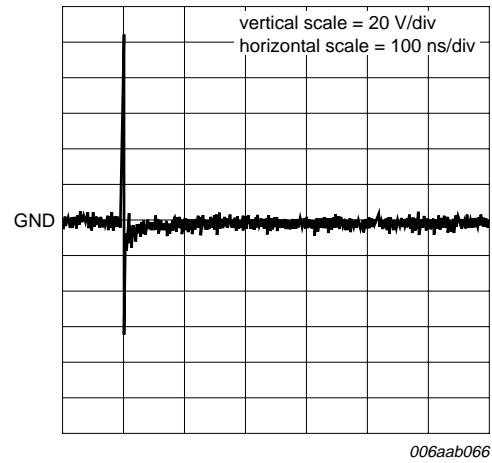


Fig 15. PESD5Z6.0: Clamped -8 kV ESD pulse waveform (IEC 61000-4-2 network)

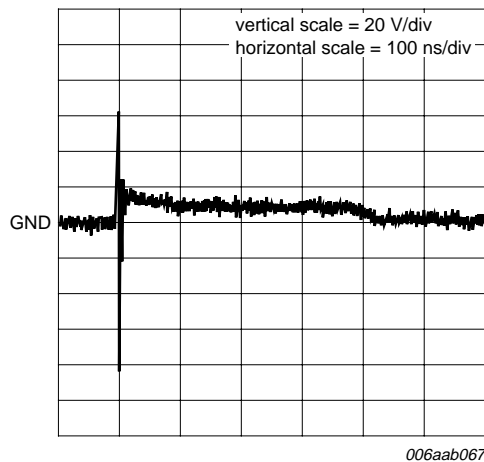


Fig 16. PESD5Z7.0: Clamped +8 kV ESD pulse waveform (IEC 61000-4-2 network)

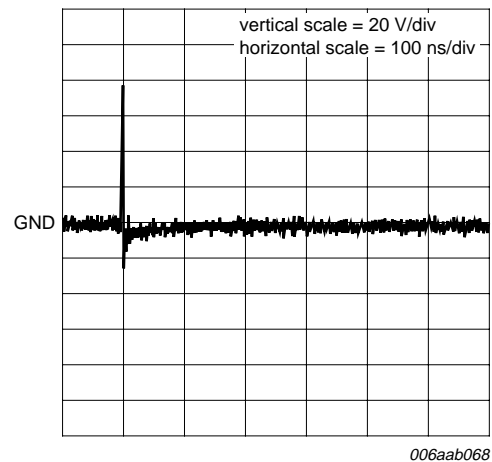
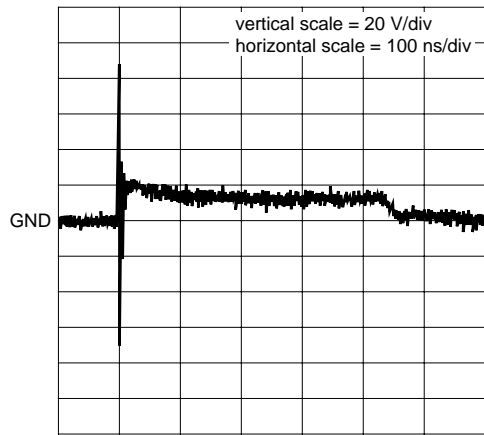
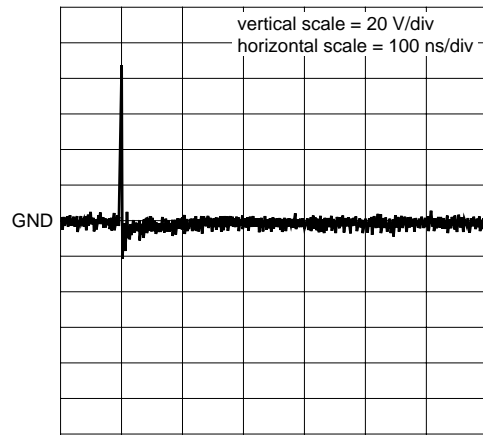


Fig 17. PESD5Z7.0: Clamped -8 kV ESD pulse waveform (IEC 61000-4-2 network)



006aab069

Fig 18. PESD5Z12: Clamped +8 kV ESD pulse waveform (IEC 61000-4-2 network)



006aab070

Fig 19. PESD5Z12: Clamped -8 kV ESD pulse waveform (IEC 61000-4-2 network)

7. Application information

The PESD5Zx series is designed for the protection of one unidirectional data or signal line from the damage caused by ESD and surge pulses. The device may be used on lines where the signal polarities are either positive or negative with respect to ground. The PESD5Zx series provides a surge capability of 260 W per line for an 8/20 μ s waveform.

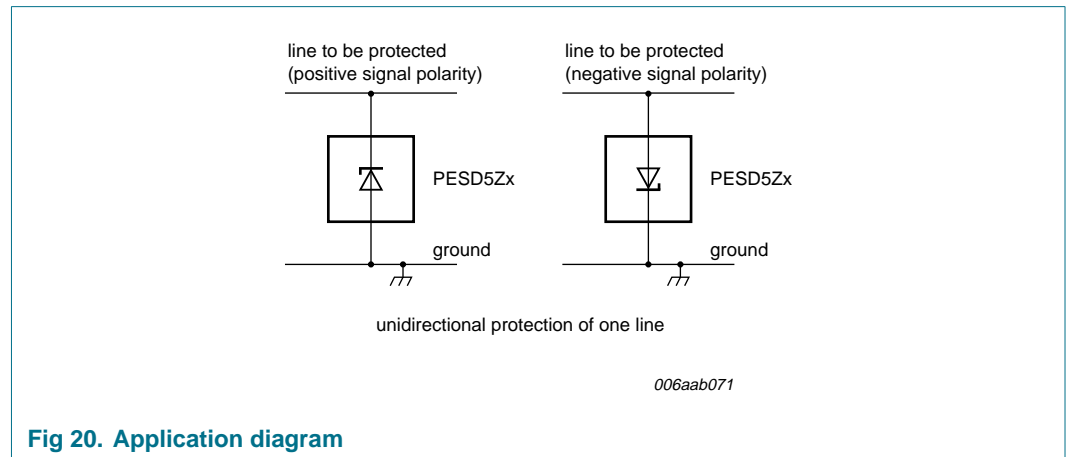


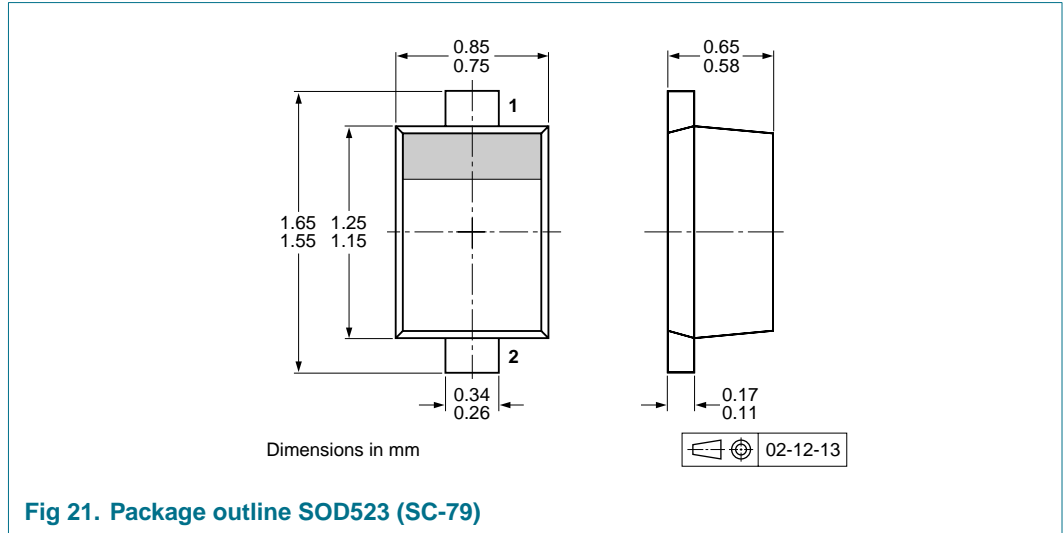
Fig 20. Application diagram

Circuit board layout and protection device placement

Circuit board layout is critical for the suppression of ESD, Electrical Fast Transient (EFT) and surge transients. The following guidelines are recommended:

1. Place the PESD5Zx as close to the input terminal or connector as possible.
2. The path length between the PESD5Zx and the protected line should be minimized.
3. Keep parallel signal paths to a minimum.
4. Avoid running protected conductors in parallel with unprotected conductors.
5. Minimize all Printed-Circuit Board (PCB) conductive loops including power and ground loops.
6. Minimize the length of the transient return path to ground.
7. Avoid using shared transient return paths to a common ground point.
8. Ground planes should be used whenever possible. For multilayer PCBs, use ground vias.

8. Package outline



9. Packing information

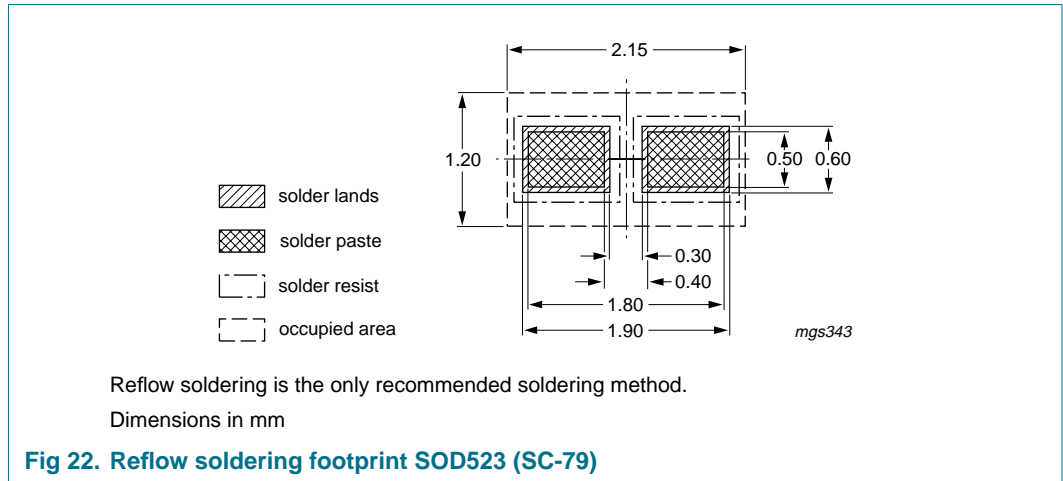
Table 10. Packing methods

The indicated -xxx are the last three digits of the 12NC ordering code.^[1]

| Type number | Package | Description | Packing quantity | | |
|-------------|---------|--------------------------------|------------------|------|-------|
| | | | 3000 | 8000 | 10000 |
| PESD5Z2.5 | SOD523 | 2 mm pitch, 8 mm tape and reel | - | -315 | - |
| | | 4 mm pitch, 8 mm tape and reel | -115 | - | -135 |
| PESD5Z3.3 | SOD523 | 2 mm pitch, 8 mm tape and reel | - | -315 | - |
| | | 4 mm pitch, 8 mm tape and reel | -115 | - | -135 |
| PESD5Z5.0 | SOD523 | 2 mm pitch, 8 mm tape and reel | - | -315 | - |
| | | 4 mm pitch, 8 mm tape and reel | -115 | - | -135 |
| PESD5Z6.0 | SOD523 | 2 mm pitch, 8 mm tape and reel | - | -315 | - |
| | | 4 mm pitch, 8 mm tape and reel | -115 | - | -135 |
| PESD5Z7.0 | SOD523 | 2 mm pitch, 8 mm tape and reel | - | -315 | - |
| | | 4 mm pitch, 8 mm tape and reel | -115 | - | -135 |
| PESD5Z12 | SOD523 | 2 mm pitch, 8 mm tape and reel | - | -315 | - |
| | | 4 mm pitch, 8 mm tape and reel | -115 | - | -135 |

[1] For further information and the availability of packing methods, see [Section 13](#).

10. Soldering



11. Revision history

Table 11. Revision history

| Document ID | Release date | Data sheet status | Change notice | Supersedes |
|----------------|--|--------------------|---------------|---------------|
| PESD5ZX_SER_2 | 20080404 | Product data sheet | - | PESD5ZX_SER_1 |
| Modifications: | • Table 10 : Type number updated to PESD5Z12 | | | |
| PESD5ZX_SER_1 | 20070813 | Product data sheet | - | - |

12. Legal information

12.1 Data sheet status

| Document status ^{[1][2]} | Product status ^[3] | Definition |
|-----------------------------------|-------------------------------|---|
| Objective [short] data sheet | Development | This document contains data from the objective specification for product development. |
| Preliminary [short] data sheet | Qualification | This document contains data from the preliminary specification. |
| Product [short] data sheet | Production | This document contains the product specification. |

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

[3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL <http://www.nxp.com>.

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